

Features

- Temperature Ranges
 - Automotive-E: -40 °C to 125 °C
- 4.5 V to 5.5 V operation
- Complementary metal oxide semiconductor (CMOS) for optimum speed/power
- Low active power
137.5 mW (max.) (25 mA)
- Low standby power
137.5 μW (max.) (25 μA)
- Automatic power-down when deselected
- TTL-compatible inputs and outputs
- Easy memory expansion with \overline{CE}_1 , CE_2 , and \overline{OE} options
- Available in Pb-free 32-pin (450 mil-wide) small outline integrated circuit (SOIC) package

Functional Description

The CY621282BN is a high-performance CMOS static RAM organized as 128K words by 8 bits. Easy memory expansion is provided by an active LOW Chip Enable (\overline{CE}_1), an active HIGH Chip Enable (CE_2), and active LOW Output Enable (\overline{OE}). This device has an automatic power-down feature that reduces power consumption by more than 75% when deselected.

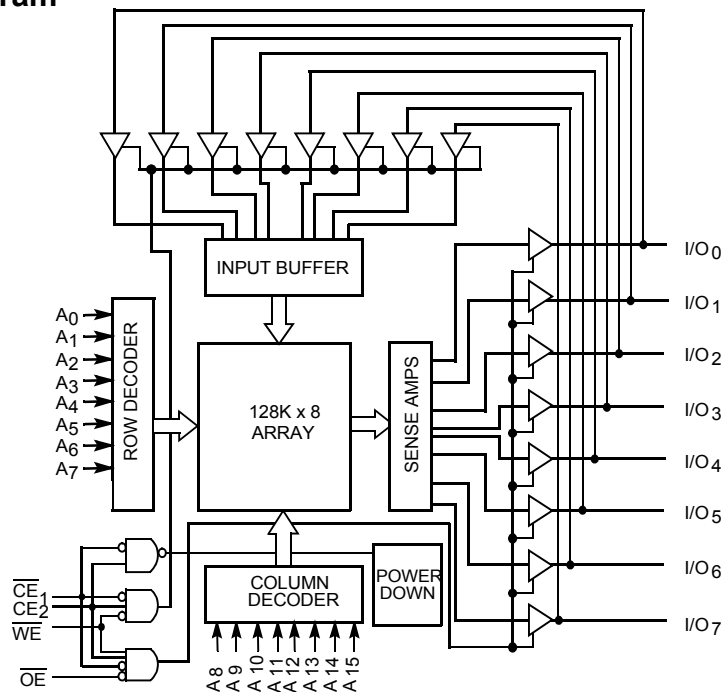
Writing to the device is accomplished by taking Chip Enable One (\overline{CE}_1) and Write Enable (\overline{WE}) inputs LOW and Chip Enable Two (CE_2) input HIGH. Data on the eight I/O pins (I/O_0 through I/O_7) is then written into the location specified on the address pins (A_0 through A_{16}).

Reading from the device is accomplished by taking Chip Enable One (\overline{CE}_1) and Output Enable (\overline{OE}) LOW while forcing Write Enable (\overline{WE}) and Chip Enable Two (CE_2) HIGH. Under these conditions, the contents of the memory location specified by the address pins will appear on the I/O pins.

The eight input/output pins (I/O_0 through I/O_7) are placed in a high-impedance state when the device is deselected (\overline{CE}_1 HIGH or CE_2 LOW), the outputs are disabled (\overline{OE} HIGH), or during a write operation (\overline{CE}_1 LOW, CE_2 HIGH, and \overline{WE} LOW).

For a complete list of related resources, [click here](#).

Logic Block Diagram



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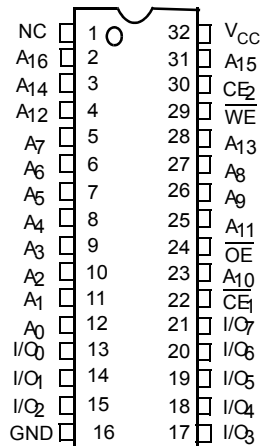
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Product Portfolio

Product		V _{CC} Range (V)			Speed (ns)	Power Dissipation			
		Min	Typ ^[1]	Max		Operating, I _{CC} (mA)		Standby, I _{SB2} (μA)	
						Typ ^[1]	Max	Typ ^[1]	Max
CY621282BN	Automotive-E	4.5	5.0	5.5	70	6	25	2.5	25

Pin Configuration

Figure 1. 32-pin SOIC (Top View)



Pin Definitions

I/O Type	Description
Input	A₀–A₁₆ . Address inputs
Input/output	I/O₀–I/O₇ . Data lines. Used as input or output lines depending on operation.
Input/control	WE . Write Enable, Active LOW. When selected LOW, a WRITE is conducted. When selected HIGH, a READ is conducted.
Input/control	CE₁ . Chip Enable 1, Active LOW.
Input/control	CE₂ . Chip Enable 2, Active HIGH.
Input/control	OE . Output Enable, Active LOW. Controls the direction of the I/O pins. When LOW, the I/O pins behave as outputs. When deasserted HIGH, I/O pins are tri-stated, and act as input data pins.
Ground	GND . Ground for the device.
Power supply	V_{CC} . Power supply for the device.

Note

1. Typical values are included for reference only and are not tested or guaranteed. Typical values are measured at V_{CC} = 5.0 V, T_A = 25 °C.

Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage temperature	-65 °C to +150 °C
Ambient temperature with power applied	-55 °C to +125 °C
Supply voltage on V _{CC} to relative GND ^[2]	-0.5 V to +7.0 V
DC voltage applied to outputs in High Z state ^[2]	-0.5 V to V _{CC} + 0.5 V

DC input voltage ^[2, 3]	-0.5 V to V _{CC} + 0.5 V
Current into outputs (LOW)	20 mA
Static discharge voltage (per MIL-STD-883, Method 3015)	> 2001 V
Latch-up current	> 200 mA

Operating Range

Range	Ambient Temperature	V _{CC}
Automotive-E	-40 °C to +125 °C	5 V ± 10%

Electrical Characteristics

Over the Operating Range

Parameter	Description	Test Conditions	-70			Unit
			Min	Typ ^[4]	Max	
V _{OH}	Output HIGH voltage	V _{CC} = 4.5 V, I _{OH} = -1.0 mA	2.4	-	-	V
		V _{CC} = 5.5 V, I _{OH} = -0.1 mA	3.95	-	-	
		V _{CC} = 5 V, I _{OH} = -0.1 mA	3.6	-	-	
		V _{CC} = 4.5 V, I _{OH} = -0.1 mA	3.25	-	-	
V _{OL}	Output LOW voltage	V _{CC} = 4.5 V, I _{OL} = 2.1 mA	-	-	0.4	V
V _{IH}	Input HIGH voltage		2.2	-	V _{CC} + 0.3	V
V _{IL}	Input LOW voltage ^[2]		-0.3	-	0.8	V
I _{IX}	Input leakage current	GND ≤ V _{IN} ≤ V _{CC}	-10	-	+10	μA
I _{OZ}	Output leakage current	GND ≤ V _{IN} ≤ V _{CC} , Output Disabled	-10	-	+10	μA
I _{CC}	V _{CC} operating supply current	f = f _{MAX} = 1/t _{RC}	-	6	25	mA
		f = 1 MHz		2	12	
I _{SB1}	Automatic CE power-down current – TTL inputs	V _{CC} = 5.5 V, $\overline{CE}_1 \geq V_{IH}$ or CE ₂ ≤ V _{IL} , V _{IN} ≥ V _{IH} or V _{IN} ≤ V _{IL} , f = f _{MAX}	-	0.1	2	mA
I _{SB2}	Automatic CE power-down current – CMOS inputs	V _{CC} = 5.5 V, $\overline{CE}_1 \geq V_{CC} - 0.3$ V, or CE ₂ ≤ 0.3 V, V _{IN} ≥ V _{CC} - 0.3 V, or V _{IN} ≤ 0.3 V, f = 0	-	2.5	25	μA

Notes

- V_{IL} (min.) = -2.0 V for pulse durations of less than 20 ns.
- No input may exceed V_{CC} + 0.5 V.
- Typical values are included for reference only and are not tested or guaranteed. Typical values are measured at V_{CC} = 5.0 V, T_A = 25 °C.

Capacitance

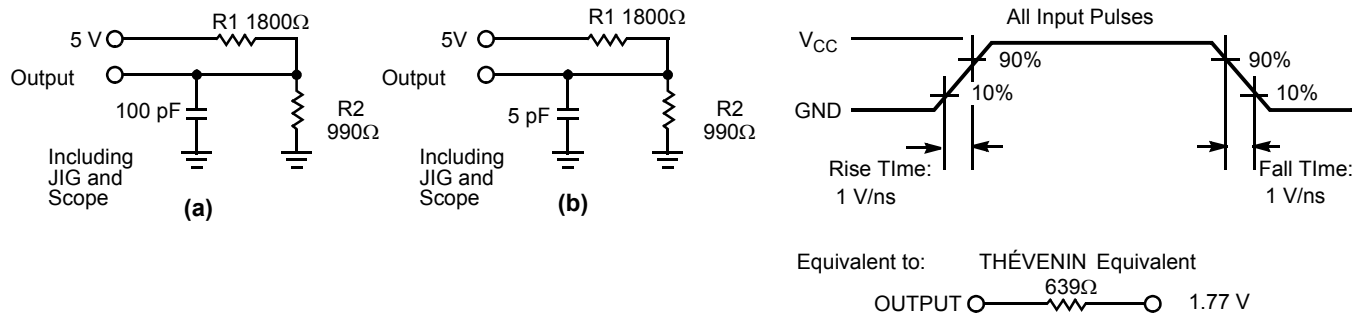
Parameter ^[5]	Description	Test Conditions	Max	Unit
C _{IN}	Input capacitance	T _A = 25 °C, f = 1 MHz, V _{CC} = 5.0 V	9	pF
C _{OUT}	Output capacitance		9	pF

Thermal Resistance

Parameter ^[5]	Description	Test Conditions	32-pin SOIC	Unit
Θ _{JA}	Thermal resistance (junction to ambient)	Test conditions follow standard test methods and procedures for measuring thermal impedance, per EIA / JESD51.	66.17	°C/W
Θ _{JC}	Thermal resistance (junction to case)		30.87	°C/W

AC Test Loads and Waveforms

Figure 2. AC Test Loads and Waveforms

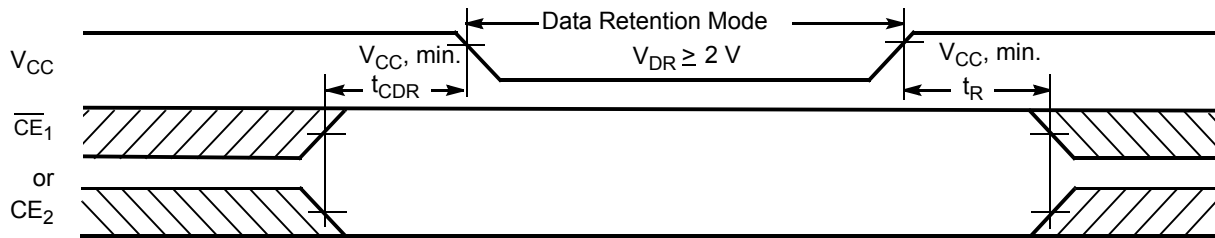


Note

5. Tested initially and after any design or process changes that may affect these parameters.

Data Retention Waveform

Figure 3. Data Retention Waveform



Data Retention Characteristics

Over the Operating Range

Parameter	Description	Conditions	Min	Typ	Max	Unit
V_{DR}	V_{CC} for data retention		2.0	–	–	V
I_{CCDR}	Data retention current	$V_{CC} = V_{DR} = 2.0\text{ V}$, $CE_1 \geq V_{CC} - 0.3\text{ V}$, or $CE_2 \leq 0.3\text{ V}$, $V_{IN} \geq V_{CC} - 0.3\text{ V}$ or, $V_{IN} \leq 0.3\text{ V}$	–	1.5	25	μA
t_{CDR}	Chip deselect to data retention time		0	–	–	ns
t_R	Operation recovery time		70	–	–	ns

Switching Characteristics

Over the Operating Range

Parameter ^[6]	Description	CY621282BN-70		Unit
		Min	Max	
Read Cycle				
t_{RC}	Read cycle time	70	–	ns
t_{AA}	Address to data valid	–	70	ns
t_{OHA}	Data hold from address change	5	–	ns
t_{ACE}	\overline{CE}_1 LOW to data valid, CE_2 HIGH to data valid	–	70	ns
t_{DOE}	\overline{OE} LOW to data valid	–	35	ns
t_{LZOE}	\overline{OE} LOW to Low Z ^[7]	0	–	ns
t_{HZOE}	\overline{OE} HIGH to High Z ^[7, 8]	–	25	ns
t_{LZCE}	\overline{CE}_1 LOW to Low Z, CE_2 HIGH to Low Z ^[7]	5	–	ns
t_{HZCE}	\overline{CE}_1 HIGH to High Z, CE_2 LOW to High Z ^[7, 8]	–	25	ns
t_{PU}	\overline{CE}_1 LOW to Power-up, CE_2 HIGH to power-up	0	–	ns
t_{PD}	\overline{CE}_1 HIGH to Power-down, CE_2 LOW to power-down	–	70	ns
Write Cycle ^[9, 10]				
t_{WC}	Write cycle time	70	–	ns
t_{SCE}	\overline{CE}_1 LOW to Write End, CE_2 HIGH to write end	60	–	ns
t_{AW}	Address set-up to write end	60	–	ns
t_{HA}	Address hold from write end	0	–	ns
t_{SA}	Address set-up to write start	0	–	ns
t_{PWE}	\overline{WE} pulse width	50	–	ns
t_{SD}	Data set-up to write end	30	–	ns
t_{HD}	Data Hold from write end	0	–	ns
t_{LZWE}	\overline{WE} HIGH to Low Z ^[7]	5	–	ns
t_{HZWE}	\overline{WE} LOW to High Z ^[7, 8]	–	25	ns

Notes

- Test conditions assume signal transition time of 5 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and output loading of the specified I_{OL}/I_{OH} and 100-pF load capacitance.
- At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE} , t_{HZOE} is less than t_{LZOE} , and t_{HZWE} is less than t_{LZWE} for any given device.
- t_{HZOE} , t_{HZCE} , and t_{HZWE} are specified with a load capacitance of 5 pF as in (b) of [Figure 2 on page 5](#). Transition is measured ± 500 mV from steady-state voltage.
- The internal write time of the memory is defined by the overlap of \overline{CE}_1 LOW, CE_2 HIGH, and \overline{WE} LOW. \overline{CE}_1 and \overline{WE} must be LOW and CE_2 HIGH to initiate a write, and the transition of any of these signals can terminate the write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the write.
- The minimum write cycle pulse width for Write Cycle No. 3 (\overline{WE} controlled, \overline{OE} LOW) should be equal to the sum of t_{SD} and t_{HZWE} .

Switching Waveforms

Figure 4. Read Cycle No. 1 [11, 12]

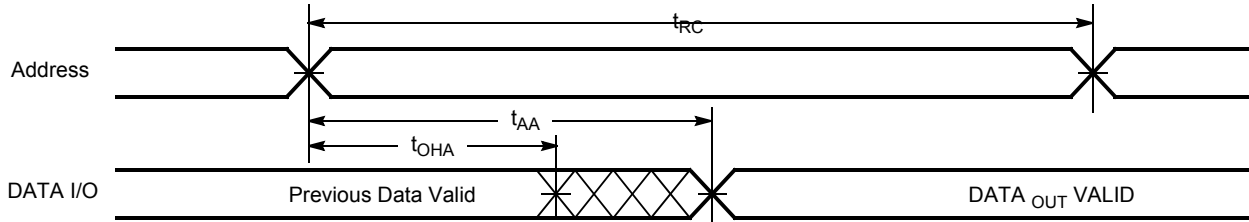


Figure 5. Read Cycle No. 2 (\overline{OE} Controlled) [12, 13]

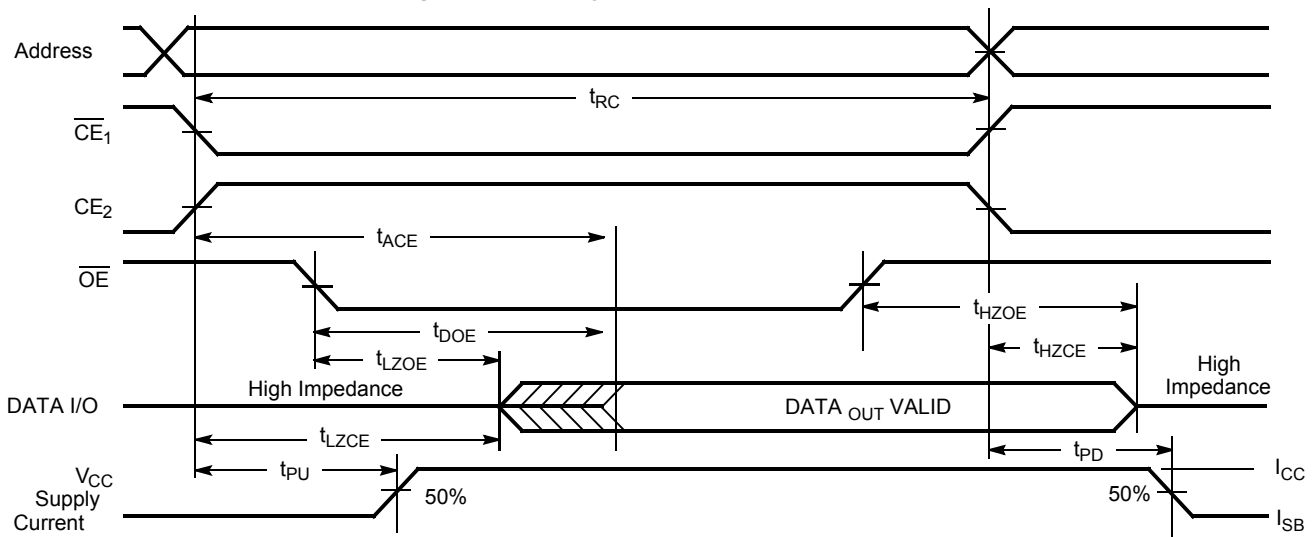
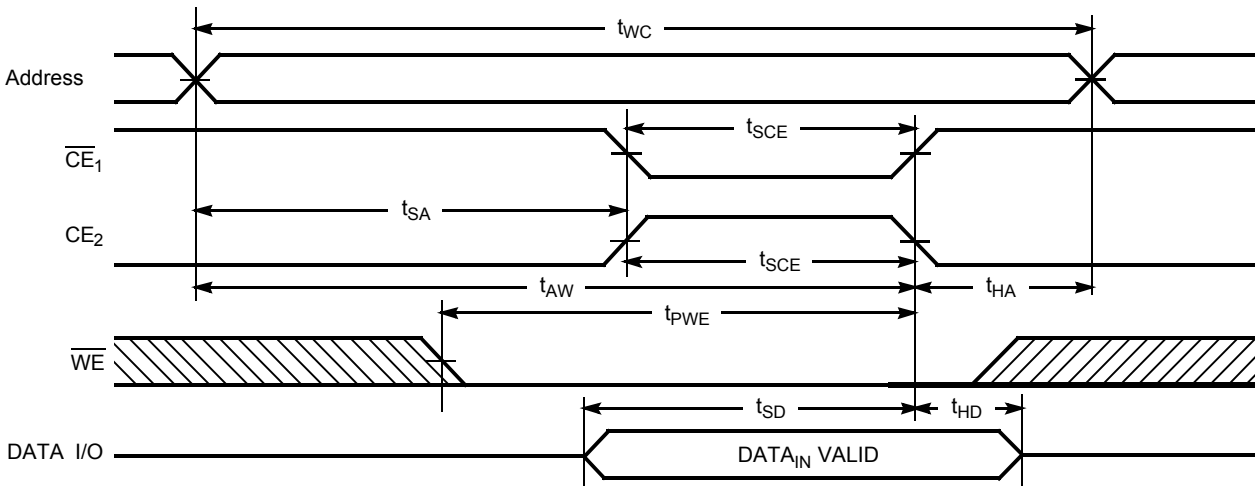


Figure 6. Write Cycle No. 1 (\overline{CE}_1 or CE_2 Controlled) [14, 15]



Notes

- 11. Device is continuously selected. \overline{OE} , $\overline{CE}_1 = V_{IL}$, $CE_2 = V_{IH}$.
- 12. WE is HIGH for read cycle.
- 13. Address valid prior to or coincident with \overline{CE}_1 transition LOW and CE_2 transition HIGH.
- 14. Data I/O is high impedance if $\overline{OE} = V_{IH}$.
- 15. If \overline{CE}_1 goes HIGH or CE_2 goes LOW simultaneously with \overline{WE} going HIGH, the output remains in a high-impedance state.

Switching Waveforms (continued)

Figure 7. Write Cycle No. 2 (\overline{WE} Controlled, \overline{OE} HIGH during Write) [16, 17]

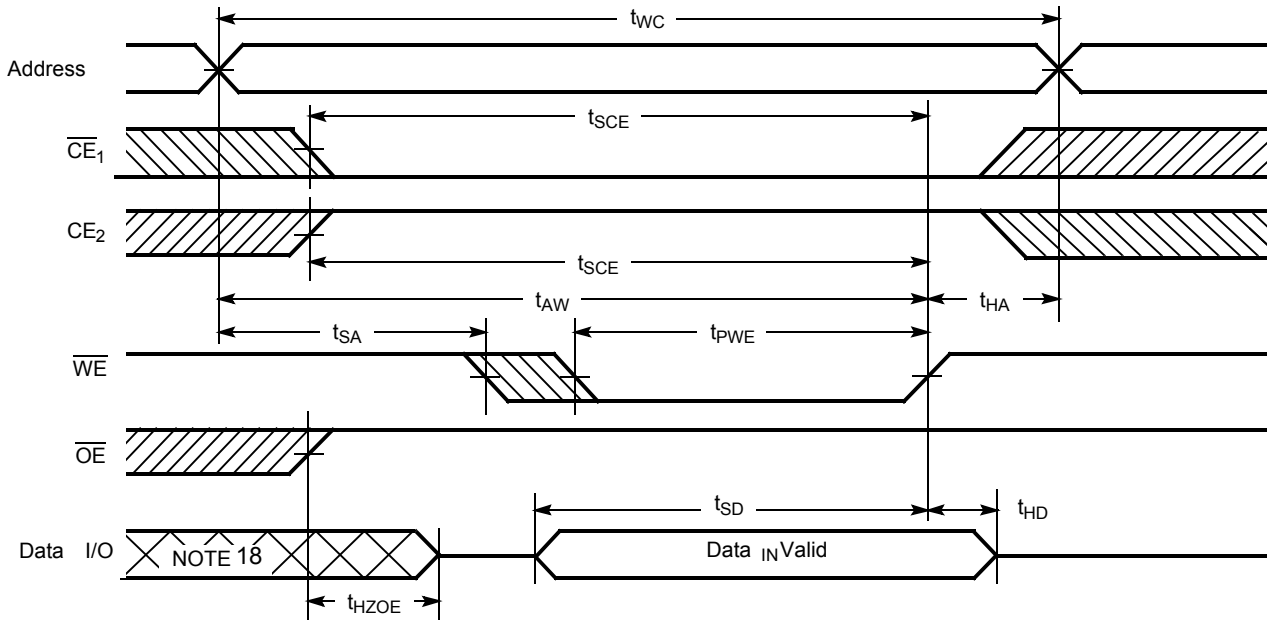
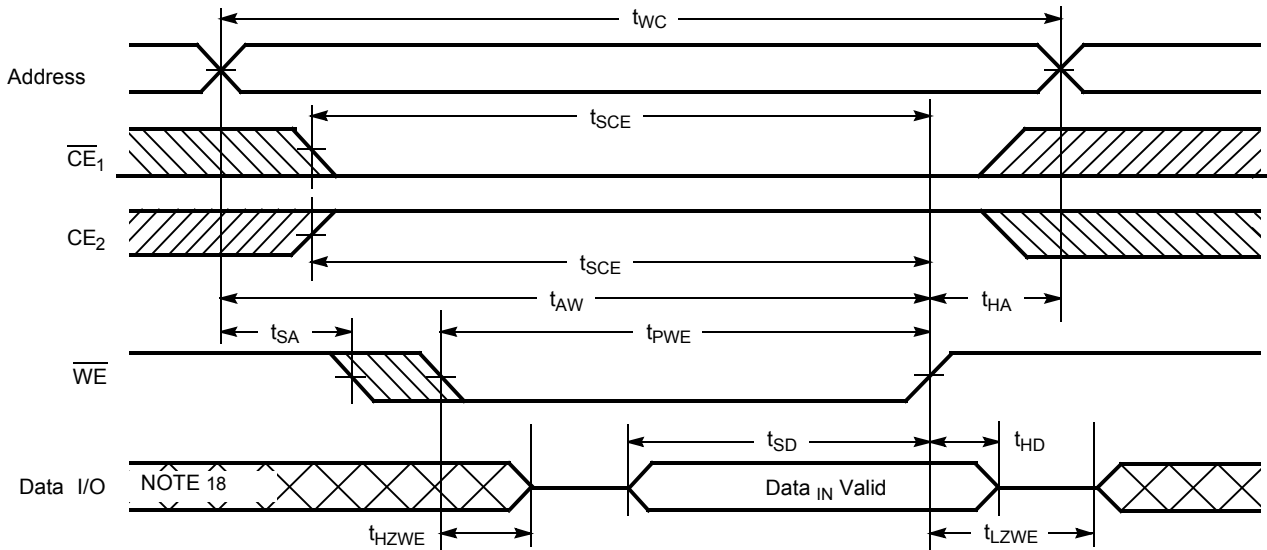


Figure 8. Write Cycle No. 3 (\overline{WE} Controlled, \overline{OE} LOW) [16, 17, 19]



Notes

- 16. Data I/O is high impedance if $\overline{OE} = V_{IH}$.
- 17. If \overline{CE}_1 goes HIGH or \overline{CE}_2 goes LOW simultaneously with \overline{WE} going HIGH, the output remains in a high-impedance state.
- 18. During this period the I/Os are in the output state and input signals should not be applied.
- 19. The minimum write cycle pulse width for Write Cycle No. 3 (\overline{WE} Controlled, \overline{OE} LOW) should be equal to the sum of t_{SD} and t_{HZWE} .

Truth Table

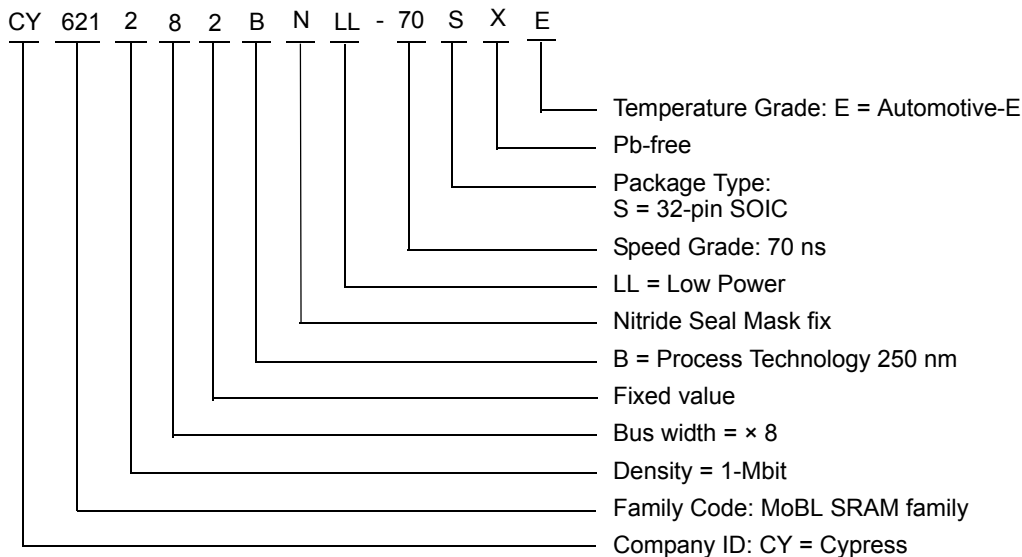
\overline{CE}_1	\overline{CE}_2	\overline{OE}	\overline{WE}	I/O ₀ -I/O ₇	Mode	Power
H	X	X	X	High Z	Power-down	Standby (I _{SB})
X	L	X	X	High Z	Power-down	Standby (I _{SB})
L	H	L	H	Data out	Read	Active (I _{CC})
L	H	X	L	Data in	Write	Active (I _{CC})
L	H	H	H	High Z	Selected, Outputs disabled	Active (I _{CC})

Ordering Information

Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
70	CY621282BNLL-70SX E	51-85081	32-pin 450-Mil SOIC (Pb-free)	Automotive-E

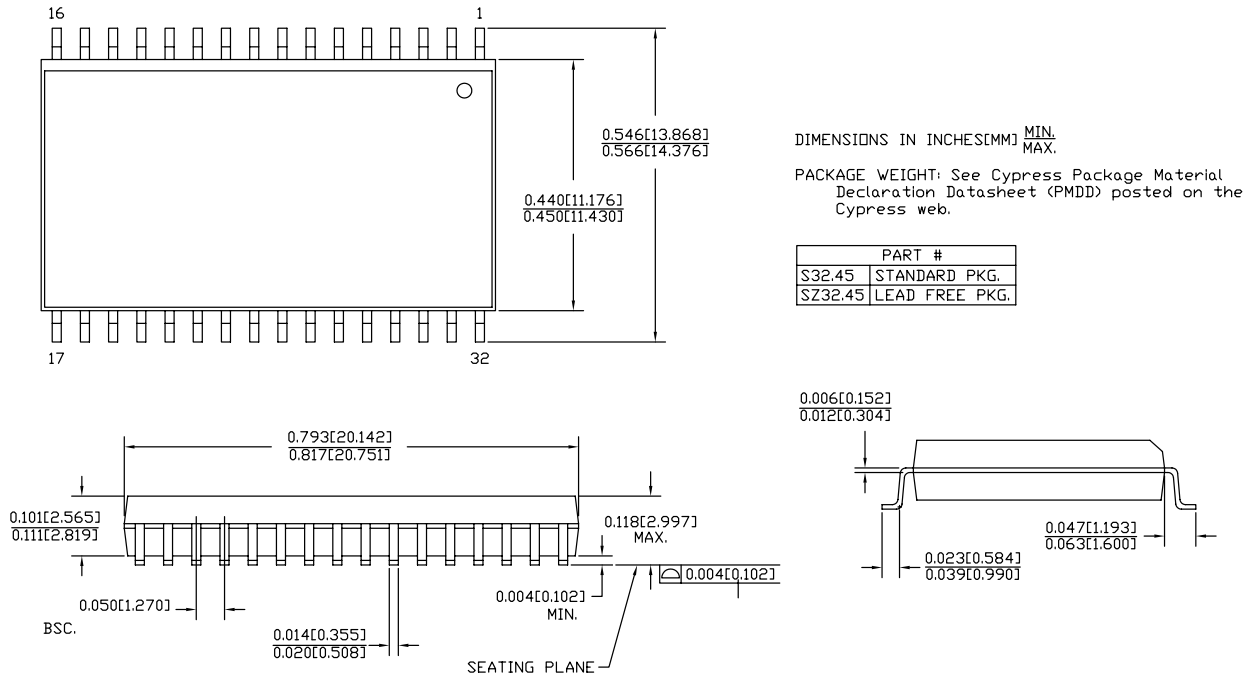
Please contact your local Cypress sales representative for availability of these parts.

Ordering Code Definitions



Package Diagrams

Figure 9. 32-pin Molded SOIC (450 Mils) S32.45/SZ32.45, 51-85081



51-85081 *E

Acronyms

Acronym	Description
\overline{CE}	Chip Enable
CMOS	Complementary Metal Oxide Semiconductor
I/O	Input/Output
\overline{OE}	Output Enable
SOIC	Small Outline Integrated Circuit
SRAM	Static Random Access Memory
TTL	Transistor-Transistor Logic
\overline{WE}	Write Enable

Document Conventions

Units of Measure

Symbol	Unit of Measure
°C	degree Celsius
MHz	megahertz
μA	microampere
μs	microsecond
mA	milliampere
mV	millivolt
mW	milliwatt
ns	nanosecond
Ω	ohm
%	percent
pF	picofarad
V	volt
W	watt

Document History Page

Document Title: CY621282BN MoBL [®] Automotive, 1-Mbit (128 K × 8) Static RAM				
Document Number: 001-65526				
Rev.	ECN No.	Issue Date	Orig. of Change	Description of Change
**	3115909	01/06/2011	RAME	New data sheet.
*A	3288690	06/21/2011	RAME	Updated Functional Description : Removed the Note "For best-practice recommendations, please refer to the Cypress application note "System Design Guidelines" on http://www.cypress.com website." and its reference. Updated to new template.
*B	3538379	03/05/2012	TAVA	Updated Electrical Characteristics . Updated Switching Waveforms . Updated Package Diagrams .
*C	4703739	03/27/2015	MEMJ	Updated Switching Characteristics : Added Note 10 and referred the same note in "Write Cycle". Updated Switching Waveforms : Added Note 19 and referred the same note in Figure 8 . Updated Package Diagrams : spec 51-85081 – Changed revision from *D to *E. Updated to new template. Completing Sunset Review.
*D	4725832	04/15/2015	PSR	Updated Functional Description : Added "For a complete list of related resources, click here ." at the end.

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